onsemi

Bipolar Transistor

160 V, 1.5 A, Low V_{CE(sat)} NPN Single LFPAK

NST1602CL

This device is bipolar junction transistor featuring high current, low saturation voltage, and high speed switching.

Suitable for automotive applications. AEC–Q101 qualified and PPAP capable. (NSVT1602CLTW)

Features

- Complement to NST1601CL
- Large Current Capacitance
- Low Collector to Emitter Saturation Voltage
- Thin Profile LFPAK8 3.3 x 3.3 mm Package
- High–Speed Switching
- High Allowable Power Dissipation
- AEC–Q101 Qualified and PPAP Capable (NSVT1602CLTW)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Load Switch
- Gate Driver Buffer
- DC–DC Converters

Specifications

ABSOLUTE MAXIMUM RATING at Ta = 25°C

Parameter	Symbol	Value	Unit
Collector-to-Base Voltage	V _{CBO}	180	V
Collector-to-Emitter Voltage	V _{CEO}	160	V
Emitter-to-Base Voltage	V _{EBO}	6	V
Collector Current	۱ _C	1.5	А
Collector Current (Pulse)	I _{CP}	2.5	А
Collector Dissipation	P _C (Note 1)	0.8	W
	P _C (Note 2)	2.2	
Junction Temperature	TJ	175	°C
Storage Temperature Range	T _{stg}	-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

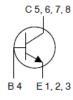
1. Mounted on FRB with minimum pad of Copper 2 oz

2. Mounted on FRB with 1 in/sq pad of Copper 2 oz



LFPAK8 3.3x3.3, 0.65P CASE 760AD

ELECTRICAL CONNECTION



MARKING DIAGRAM



NST1602 = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- Y = Year

А

- W = Work Week
- G = Pb–Free Package

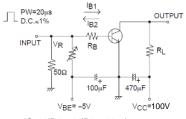
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS at Ta = 25°C

				Value		
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	VCB = 180 V IE = 0 A			0.1	μΑ
Emitter Cutoff Current	I _{EBO}	VEB = 6 V IC = 0 A			0.1	μΑ
DC Current Gain	h _{FE1}	VCE = 5 V IC = 100 mA	140		280	
	h _{FE2}	VCE = 5 V IC = 400 mA	120			
Gain–Bandwidth Product	f _T	VCE = 10 V IC = 100 mA		100		MHz
Output Capacitance	C _{ob}	VCB = 10 V f = 1 MHz		10		pF
Collector to Emitter Saturation Voltage	V _{CE(sat)1}	IC = 250 mA IB = 25 mA		0.04	0.08	V
	V _{CE(sat)2}	IC = 250 mA IB = 50 mA		0.035	0.07	V
	V _{CE(sat)3}	IC = 500 mA IB = 50 mA		0.07	0.14	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	IC = 250 mA IB = 25 mA		0.8	1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	IC = 10 μA, IE = 0 A	180			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	IC = 1 mA, RBE = ∞	160			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	IE = 10 μA, IC = 0 A	6			V
Turn–On Time	t _{on}	See Figure 1		30		ns
Storage Time	t _{stg}]		1340		ns
Fall Time	t _f			30		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



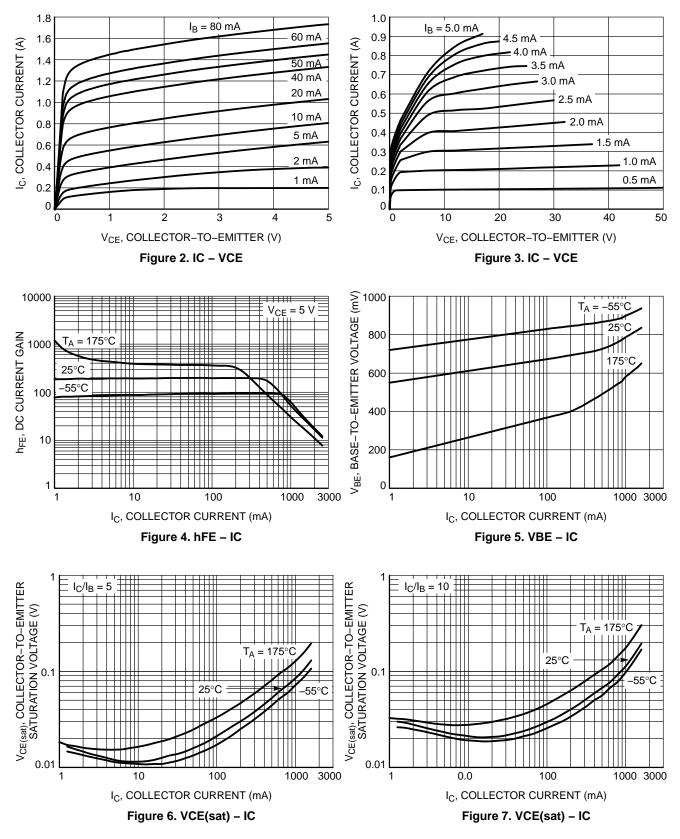
IC=10|B1=-10|B2=500mA

Figure 1. Switching Time Test Circuit

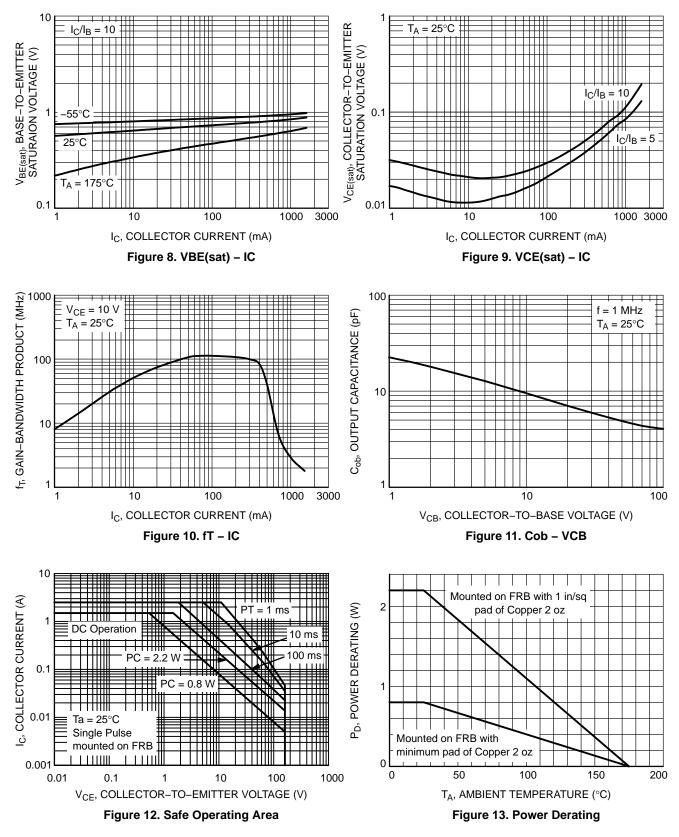
ESD RATING

Parameter	Symbol	Value	Unit	Class
Electrostatic Discharge – Human Body Model	HBM	>2000, <4000	V	2
Electrostatic Discharge – Machine Model	MM	>400	V	M4

TYPICAL CHARACTERISTICS







ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing) [†]
NSVT1602CLTWG	NST1602G	LFPAK8 (Pb–Free / Halogen Free)	3,000 / Tape & Reel
NST1602CLTWG	NST1602G	LFPAK8 (Pb–Free / Halogen Free)	3,000 / Tape & Reel

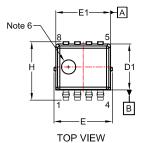
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

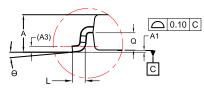
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

LFPAK8 3.3x3.3, 0.65P CASE 760AD ISSUE E

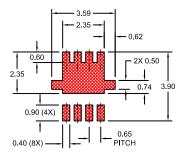
DATE 16 NOV 2020

DUSEM





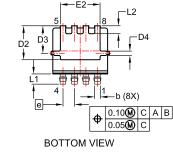
DETAIL 'A' SCALE: 2:1



LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14 5M, 1994
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS OR BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
- 4. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- DATUMS A AND B ARE DETERMINED AT DATUM 5 PLANE H. 6. OPTIONAL MOLD FEATURE.

DIM	MILLIMETERS			
Dim	MIN.	NOM.	MAX.	
A	0.95	1.05	1.15	
A1	0.00	0.05	0.10	
A2	0.95	1.00	1.05	
A3		0.15 RE	F	
b	0.27	0.32	0.37	
с	0.12	0.17	0.22	
c2	0.12	0.17	0.22	
D1	2.50	2.60	2.70	
D2	1.82	1.92	2.02	
D3	1.46	1.56	1.66	
D4	0.20	0.25	0.30	
E	3.20	3.30	3.40	
E1	3.00	3.10	3.20	
E2	2.15	2.25	2.35	
е	0.65 BSC			
Н	3.20	3.30	3.40	
L	0.25	0.37	0.50	
L1	0.48	0.58	0.68	
L2	0.35	0.45	0.55	
Q	0.45	0.50	0.55	
θ	0°	4°	8°	

GENERIC **MARKING DIAGRAM***

	XXXXX
	XXXXX
	AWLYW
۰	

XXXX = Specific Device Code

- = Assembly Location А
- = Wafer Lot WL Y

= Year

W = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

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